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Should be replaced with:

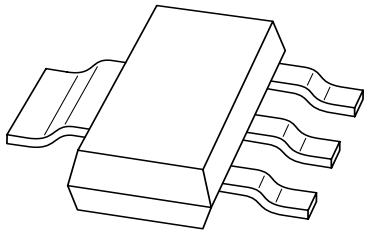
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Kind regards,

Team Nexperia

# DATA SHEET



## **BF720; BF722** NPN high-voltage transistors

Product data sheet  
Supersedes data of 1996 Dec 05

1999 Apr 21

## NPN high-voltage transistors

## BF720; BF722

## FEATURES

- Low feedback capacitance.

## APPLICATIONS

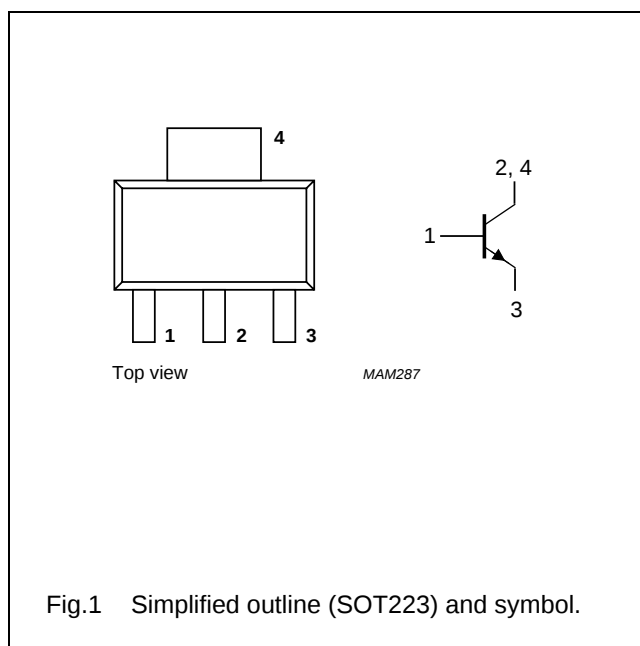
- Class-B video output stages of colour television receivers
- General purpose high voltage circuits.

## DESCRIPTION

NPN transistors in a SOT223 plastic package.  
PNP complement: BF723.

## PINNING

| PIN  | DESCRIPTION |
|------|-------------|
| 1    | base        |
| 2, 4 | collector   |
| 3    | emitter     |



## LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

| SYMBOL    | PARAMETER                                   | CONDITIONS                           | MIN.   | MAX.       | UNIT   |
|-----------|---------------------------------------------|--------------------------------------|--------|------------|--------|
| $V_{CBO}$ | collector-base voltage<br>BF720<br>BF722    | open emitter                         | —<br>— | 300<br>250 | V<br>V |
| $V_{CEO}$ | collector-emitter voltage<br>BF720<br>BF722 | open base                            | —<br>— | 300<br>250 | V<br>V |
| $V_{EBO}$ | emitter-base voltage                        | open collector                       | —      | 5          | V      |
| $I_C$     | collector current (DC)                      |                                      | —      | 100        | mA     |
| $I_{CM}$  | peak collector current                      |                                      | —      | 200        | mA     |
| $I_{BM}$  | peak base current                           |                                      | —      | 100        | mA     |
| $P_{tot}$ | total power dissipation                     | $T_{amb} \leq 25\text{ °C}$ ; note 1 | —      | 1.2        | W      |
| $T_{stg}$ | storage temperature                         |                                      | –65    | +150       | °C     |
| $T_j$     | junction temperature                        |                                      | —      | 150        | °C     |
| $T_{amb}$ | operating ambient temperature               |                                      | –65    | +150       | °C     |

## Note

1. Device mounted on printed-circuit board, single sided copper, tinplated, mounting pad for collector 1 cm<sup>2</sup>. For other mounting conditions, see “Thermal considerations for SOT223 in the General Part of associated Handbook”.

## NPN high-voltage transistors

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## THERMAL CHARACTERISTICS

| SYMBOL        | PARAMETER                                           | CONDITIONS | VALUE | UNIT |
|---------------|-----------------------------------------------------|------------|-------|------|
| $R_{th\ j-a}$ | thermal resistance from junction to ambient         | note 1     | 106   | K/W  |
| $R_{th\ j-s}$ | thermal resistance from junction to soldering point | note 1     | 25    | K/W  |

## Note

1. Device mounted on printed-circuit board, single sided copper, tinplated, mounting pad for collector 1 cm<sup>2</sup>.  
For other mounting conditions, see *"Thermal considerations for SOT223 in the General Part of associated Handbook"*.

## CHARACTERISTICS

$T_j = 25\text{ °C}$  unless otherwise specified.

| SYMBOL      | PARAMETER                            | CONDITIONS                                                     | MIN. | MAX. | UNIT |
|-------------|--------------------------------------|----------------------------------------------------------------|------|------|------|
| $I_{CBO}$   | collector cut-off current            | $I_E = 0; V_{CB} = 200\text{ V}$                               | –    | 10   | nA   |
|             |                                      | $I_E = 0; V_{CB} = 200\text{ V}; T_j = 150\text{ °C}$          | –    | 10   | μA   |
| $I_{EBO}$   | emitter cut-off current              | $I_C = 0; V_{EB} = 5\text{ V}$                                 | –    | 50   | nA   |
| $h_{FE}$    | DC current gain                      | $I_C = 25\text{ mA}; V_{CE} = 20\text{ V}$                     | 50   | –    |      |
| $V_{CEsat}$ | collector-emitter saturation voltage | $I_C = 30\text{ mA}; I_B = 5\text{ mA}$                        | –    | 0.6  | V    |
| $C_{re}$    | feedback capacitance                 | $I_C = i_c = 0; V_{CE} = 30\text{ V}; f = 1\text{ MHz}$        | –    | 1.6  | pF   |
| $f_T$       | transition frequency                 | $I_C = 10\text{ mA}; V_{CE} = 10\text{ V}; f = 100\text{ MHz}$ | 60   | –    | MHz  |

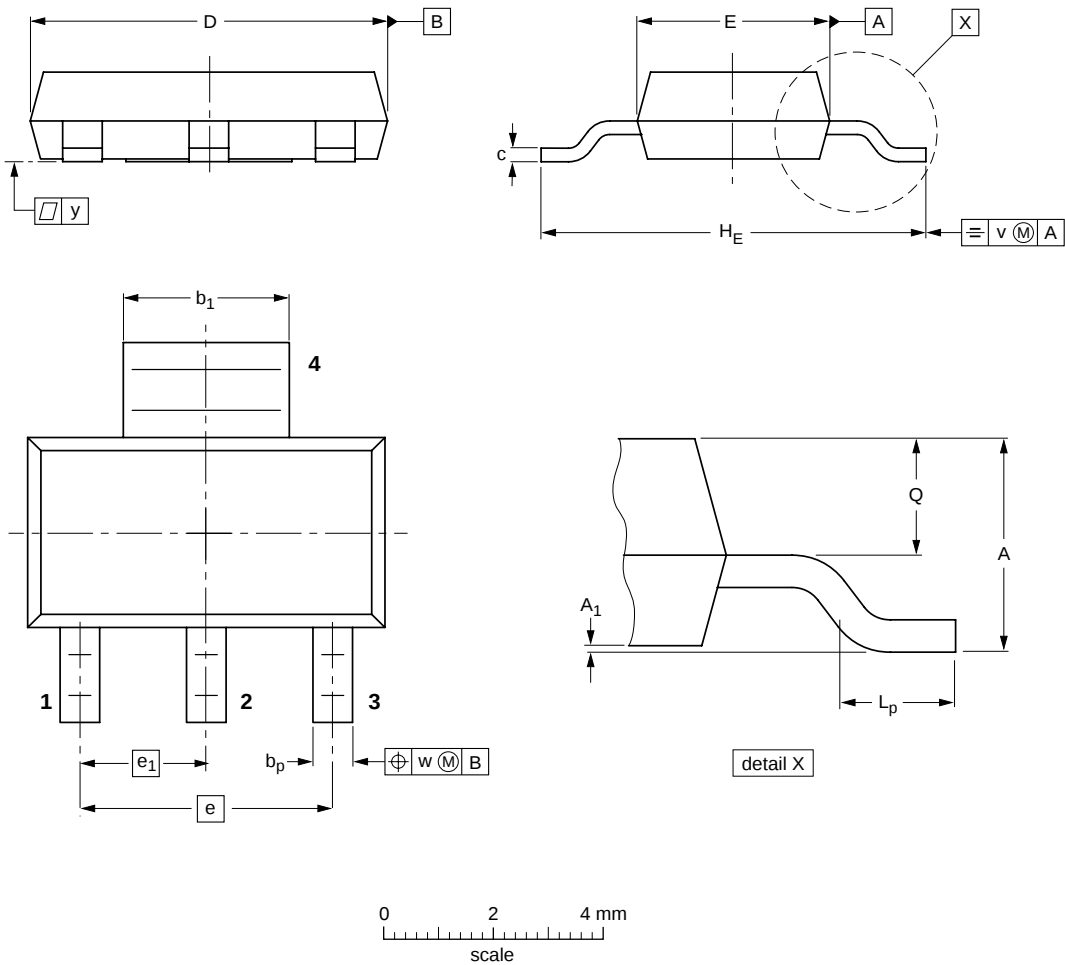
NPN high-voltage transistors

BF720; BF722

PACKAGE OUTLINE

Plastic surface mounted package; collector pad for good heat transfer; 4 leads

SOT223



DIMENSIONS (mm are the original dimensions)

| UNIT | A          | A <sub>1</sub> | b <sub>p</sub> | b <sub>1</sub> | c            | D          | E          | e   | e <sub>1</sub> | H <sub>E</sub> | L <sub>p</sub> | Q            | v   | w   | y   |
|------|------------|----------------|----------------|----------------|--------------|------------|------------|-----|----------------|----------------|----------------|--------------|-----|-----|-----|
| mm   | 1.8<br>1.5 | 0.10<br>0.01   | 0.80<br>0.60   | 3.1<br>2.9     | 0.32<br>0.22 | 6.7<br>6.3 | 3.7<br>3.3 | 4.6 | 2.3            | 7.3<br>6.7     | 1.1<br>0.7     | 0.95<br>0.85 | 0.2 | 0.1 | 0.1 |

| OUTLINE<br>VERSION | REFERENCES |       |       |  | EUROPEAN<br>PROJECTION                                                                | ISSUE DATE           |
|--------------------|------------|-------|-------|--|---------------------------------------------------------------------------------------|----------------------|
|                    | IEC        | JEDEC | EIAJ  |  |                                                                                       |                      |
| SOT223             |            |       | SC-73 |  |  | 97-02-28<br>99-09-13 |

## NPN high-voltage transistors

## BF720; BF722

## DATA SHEET STATUS

| DOCUMENT STATUS <sup>(1)</sup> | PRODUCT STATUS <sup>(2)</sup> | DEFINITION                                                                            |
|--------------------------------|-------------------------------|---------------------------------------------------------------------------------------|
| Objective data sheet           | Development                   | This document contains data from the objective specification for product development. |
| Preliminary data sheet         | Qualification                 | This document contains data from the preliminary specification.                       |
| Product data sheet             | Production                    | This document contains the product specification.                                     |

## Notes

1. Please consult the most recently issued document before initiating or completing a design.
2. The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

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# ***NXP Semiconductors***

## **Customer notification**

This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content, except for package outline drawings which were updated to the latest version.

## **Contact information**

For additional information please visit: <http://www.nxp.com>

For sales offices addresses send e-mail to: [salesaddresses@nxp.com](mailto:salesaddresses@nxp.com)

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